

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

2SK638

FEATURES

- Drain Current $-I_D=3A@T_C=25\degreeC$
- Drain Source Voltage-
 - : V_{DSS}= 800V(Min)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

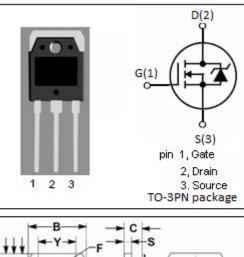
• Designed for high voltage, high speed power switching applications such as switching regulators, converters, solenoid and relay drivers.

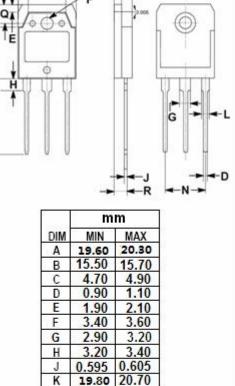
ABSOLUTE MAXIMUM RATINGS(Ta=25 C)							
SYMBOL	PARAMETER	VALUE	UNIT				
V _{DSS}	Drain-Source Voltage	800	V				
V_{GS}	Gate-Source Voltage-Continuous	±20	V				
lD	Drain Current-Continuous	3	А				
P _D	Total Dissipation @T _c =25°C	80	W				
TJ	Max. Operating Junction Temperature	150	°C				
T _{stg}	T _{stg} Storage Temperature -55~150		°C				

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case 1.25		°C/W
R _{th j-a}	Thermal Resistance, Junction to Ambient	62.5	°C/W





1.90

4.90

3.35

5.90

1.995

10.89

N

Q

R

s

U

Y

2.20

5.10

3.45

2.100

6.20

9.90 | 10.10

10.91

¹ isc & iscsemi is registered trademark

isc website: <u>www.iscsemi.com</u>



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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25^{\circ}\!\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBO L	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 0.25mA	800			V
$V_{GS(th)}$	Gate Threshold Voltage	V_{DS} = V_{GS} ; I_D = 1mA	1.0		5.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 15V; I _D = 3A			5.0	Ω
lgss	Gate-Body Leakage Current	V _{GS} = ±20V;V _{DS} = 0			±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 800V; V _{GS} =0			250	μA

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